MN5814

TFT AV Panel Controller IC

Overview

The MN5814 is a TFT LCD panel timing controller IC.

■ Features

- Supports both composite sync and separate sync signal video inputs.
- Horizontal and vertical position adjustment function
 Horizontal: 5 bits (Adjustment range: 9.38 μs)
 Vertical: 4 bits (Adjustment range: 14 H)
- Supports multiple panel types

From 2.5-type to 7-type wide-screen panels For wide-screen panels:

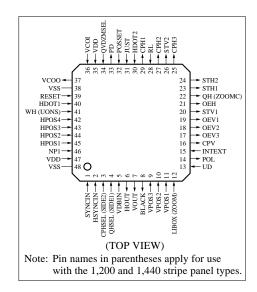
Display with black side bands (3 modes) Just-fit display Zoom (2 modes)

- Switching between PAL and NTSC (PAL: decimation only)
- Underside on-screen display (UONS)
- An optimal zooming mode is possible according to the display panel through 2-zooming mode of ZOOM1 and ZOOM2.
- UONS display at arbitrary positions is possible by the black side control pins.

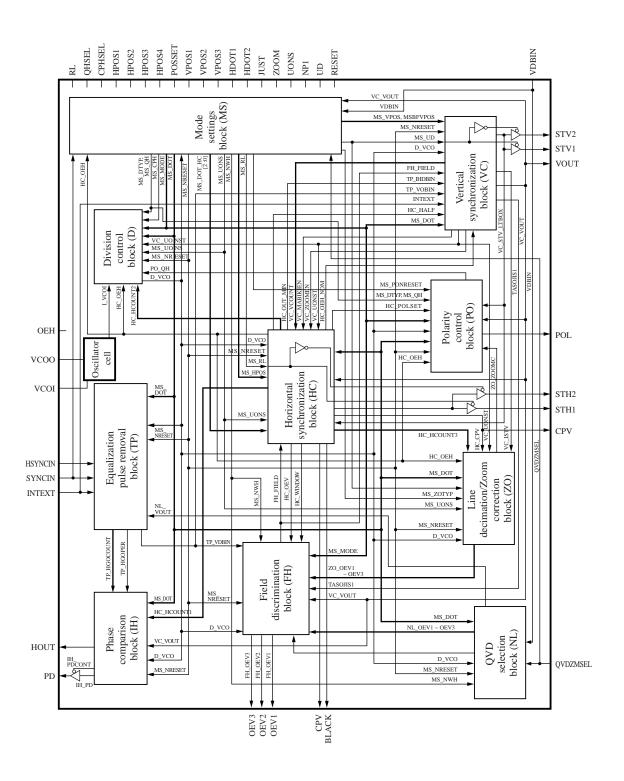
Also provides full-screen black side display.

Applications

• TFT LCD panels



■ Block Diagram



■ Pin Descriptions

Pin No.	Pin Name	I/O	Description				
1	SYNCIN	I	Composite sync input				
2	HSYNCIN	I	Horizontal sync input (separate)				
3	CPHSEL	I	In 1,440 or 1,200-stripe mode: Black side and just-fit control				
-	(SIDE2)	_	In 960-stripe mode: Disabled				
			In 480 or 960-delta mode: CPH pulse phase switching				
4	QHSEL	I	In 1,440 or 1,200-stripe mode: Black side and just-fit control				
	(SIDE1)		In 960-stripe mode: Disabled				
		_	In 480 or 960-delta mode: QH pulse phase switching				
5	VDBIN	I	Vertical sync input (separate)				
6	HOUT	О	Horizontal sync output				
7	VOUT	О	Vertical sync output				
8	BLACK	О	Black signal output				
9	VPOS3	I	Vertical display position switching (STV1 and STV2 position switching)				
10	VPOS2	I					
11	VPOS1	I					
12	LTBOX	I	High: Zoom or letterbox display				
	(ZOOM)		In 1,440 or 1,200-mode: Zoom display control				
			In 480 or 960-delta or 960-stripe mode:				
			Letterbox display control				
13	UD	1	Up/down scan direction switching (STV1 and STV2 output switching)				
14	POL	О	Video, opposite electrode reversal signal				
15	INTEXT	I	Composite/separate input switching				
16	CPV	О	Gate driver IC clock				
17	OEV3	О	Gate driver IC output stage enable pulse signals				
18	OEV2	О					
19	OEV1	О					
20	STV1	О	Gate driver IC start pulse 1				
21	OEH	О	Source driver IC output stage enable pulse signal				
22	QH	О	In 480 or 960-delta mode: Color arrangement switching pulse				
	(ZOOMC)		In 1,200 or 1,440-mode: Zoom control pulse				
			In 960 stripe mode: Fixed low-level output				
23	STH1	О	Source driver IC start pulse 1				
24	STH2	О	Source driver IC start pulse 2				
25	СРН3	О	Source driver IC clock 3				
26	STV2	О	Source driver IC start pulse 2				
27	CPH2	О	Source driver IC clock 2				
28	RL	I	Left/right scan direction switching (STH1 and STH2 output switching)				

■ Pin Descriptions (continued)

Pin No.	Pin Name	I/O	Description			
29	CPH1	О	Source driver IC clock 1			
30	HDOT2	I	Display pixel count mode switch 2			
31	JUST	I	In 1,200 or 1,440-mode: Just-fit display switching In 960-mode: Stripe/delta control			
32	POSSET	I	Horizontal/vertical display position offset switching			
33	PD	О	Phase comparator output			
34	QVDZMSEL	I	In 480 or 960-delta or stripe mode: QVD input In 1,200 or 1,400-mode: Zoom 1/zoom 2 display switching OEV pulse control in zoom mode			
35	VDD	I	Power supply (VDD)			
36	VCOI	I	VCO input (system clock input)			
37	VCOO	О	VCO output			
38	VSS	I	Ground (GND)			
39	RESET	I	System reset			
40	HDOT1	I	Display pixel count mode switching 1			
41	WH (UONS)	I	In 1,200 or 1,440-mode: "Under on-screen" display control In 480 or 960-delta or stripe mode: WH (write/hold) control			
42	HPOS4	I	Horizontal display position switching signals			
43	HPOS3	I	(STH1 and STH2 position switching)			
44	HPOS2	I				
45	HPOS1	I				
46	NP1	I	NTSC/PAL switching			
47	VDD	I	Power supply (VDD)			
48	VSS	I	Ground (GND)			



■ Electrical Characteristics

1. Absolute Maximum Ratings at V_{SS} = 0 V

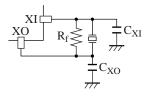
Parameter	Symbol	Rating	Unit
Supply voltage	V _{DD}	- 0.3 to +4.6	V
Input pin voltage	V _I	- 0.3 to V _{DD} +0.3	V
Output pin voltage	Vo	- 0.3 to V _{DD} +0.3	V
Output current (HL2 pins)	I _O	±6	mA
Output current (HL4 pins)	I _O	±12	mA
Power dissipation	P _D	330	mW
Operating temperature	T _{opr}	-40 to +85	°C
Storage temperature	T _{stg}	-55 to +150	°C

Note) 1. HL2 pins: QH, CPV, OEH, OEV1 to OEV3, POL, STH1, STH2, STV1, STV2, HOUT, VOUT, BLACK HL4 pins: PD, CPH1 to CPH3

- The absolute maximum ratings are limit values for stresses applied to the chip so that the chip will not be destroyed.Operation is not guaranteed within these ranges.
- 3. All the VDD and VSS pins must be connected externally to the corresponding power or ground.
- 4. The power dissipation rating applies at $T_{opr} = 85^{\circ}C$ when the MN5814 is mounted on a glass-epoxy printed circuit board. The actual value differs depending on the printed circuit board used and the thermal conditions in the end product.

2. Recommended Operating Conditions at $V_{SS} = 0 \text{ V}$

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Supply voltage	V_{DD}		2.7	3.3	3.6	V
Ambient temperature	T _a		-40	_	85	°C
Input rise time	t _r		0	_	100	ns
Input fall time	t_{f}		0	_	100	ns
Oscillator frequency	f _{OSC} 1	30 MHz Xtal	_	30	_	MHz
Recommended values for external capacitors	C _{XI} 90 C _{XO} 90	V _{DD} = 3.3 V, with an external		33 (15 MHz to 25 MHz)		pF
		feedback resistor		10 (25 MHz to 40 MHz)	_	
Recommended values for external resistors	R _f 90	$V_{\rm I} = V_{\rm DD}$ or $V_{\rm SS}$, $V_{\rm DD} = 3.3 \text{ V}$	_	2.2	_	kΩ



Note) Since the oscillator characteristics differ depending on the oscillator element used and the external capacitor conditions, consult the manufacturer of the oscillator element to determine the optimal oscillator circuit.

■ Electrical Characteristics (continued)

3. Electrical Characteristics at $V_{DD} = 2.7 \text{ V}$ to 3.6 V, $V_{SS} = 0 \text{ V}$, $f_{TEST} = 30 \text{ MHz}$, $T_a = -40 ^{\circ}\text{C}$ to $+85 ^{\circ}\text{C}$ Parameter Symbol Condition Min Typ Max U

Symbol

	Cyllibol	Condition	IVIIII	ıур	IVIAA	Offic
Quiescent supply current	$I_{ m DDS}$	V_{I} (pulled-up pins) = OPEN, V_{I} (pulled-down pins) = OPEN, V_{I} (XI) = V_{DD}^{*} , With either the V_{DD} or the V_{SS} level applied		_	500	μА
		simultaneously to all of the other input pins and I/O pins				
		in the high-impedance state.				
Operating supply current	I_{DDO}	$V_I = V_{DD}$ or V_{SS} , f = 30 MHz,	_	15	30	mA
4) 01400: 41 101 3		$V_{DD} = 3.3 \text{ V}$, outputs open	D. H31013	***		
CMOS input level Schmit			IN, HSYNC			
Input threshold voltage	VT+	$V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$		1.85	$V_{DD} \times 0.7$	V
	VT-		$V_{DD} \times 0.3$	1.45	_	
Input leakage current	I _{LI}	$V_{\rm I} = V_{\rm DD}$ or $V_{\rm SS}$	_		±5	μΑ
2) CMOS input level pins wi	th built-in	pull-up resistor: RL, UD, H	DOT1, HDC	DT2, INTE	XT	
High-level input voltage	V _{IH}		$V_{DD} \times 0.7$	_	V _{DD}	V
Low-level input voltage	V _{IL}		0		$V_{DD} \times 0.3$	V
Pull-up resistor	R _{IH}	$V_I = 0 V$	33	100	318	kΩ
Input leakage current	I_{LIH}	$V_I = V_{DD}$	_	—	±10	μΑ
3) CMOS input level pins wi	th built-in		. OHERE	DHSEI D	OGGET OVI	
	JUST, UON	NS, VPOS1 to VPOS3, ZOOM	1, QHSEL, C	TIBEL, I	OSSET, QVI	OZMSE
	JUST, UON V _{IH}	VS, VPOS1 to VPOS3, ZOON	$V_{DD} \times 0.7$	—	V _{DD}	OZMSE V
NP1, HPOS1 to HPOS4,		NS, VPOS1 to VPOS3, ZOON		— —	1 1	
NP1, HPOS1 to HPOS4, High-level input voltage	V _{IH}	NS, VPOS1 to VPOS3, ZOON $V_{I} = V_{DD}$	$V_{DD} \times 0.7$	——————————————————————————————————————	V _{DD}	V
NP1, HPOS1 to HPOS4, High-level input voltage Low-level input voltage	V _{IH}		$\begin{array}{c} V_{DD} \times 0.7 \\ \hline 0 \end{array}$	_ _	V_{DD} $V_{DD} \times 0.3$	V V
NP1, HPOS1 to HPOS4, High-level input voltage Low-level input voltage Pull-down resistor	V _{IH} V _{IL} R _{IL} I _{LIL}	$\begin{aligned} V_{I} &= V_{DD} \\ V_{I} &= V_{SS} \end{aligned}$	V _{DD} × 0.7 0 33 —		$\begin{array}{c c} V_{DD} \\ V_{DD} \times 0.3 \\ \hline 318 \\ \pm 10 \\ \end{array}$	V V kΩ
NP1, HPOS1 to HPOS4, High-level input voltage Low-level input voltage Pull-down resistor Input leakage current	V _{IH} V _{IL} R _{IL} I _{LIL}	$V_{\rm I} = V_{\rm DD}$ $V_{\rm I} = V_{\rm SS}$ EH, OEV1 to OEV3, POL, HO $I_{\rm OH} = -1.9$ mA,	V _{DD} × 0.7 0 33 —		$\begin{array}{c c} V_{DD} \\ V_{DD} \times 0.3 \\ \hline 318 \\ \pm 10 \\ \end{array}$	V V kΩ
NP1, HPOS1 to HPOS4, High-level input voltage Low-level input voltage Pull-down resistor Input leakage current 4) Push-pull output pins: QF	V_{IH} V_{IL} R_{IL} I_{LIL}	$V_{I} = V_{DD}$ $V_{I} = V_{SS}$ EH, OEV1 to OEV3, POL, HO	V _{DD} × 0.7 0 33 — OUT, VOUT		$\begin{array}{c c} V_{DD} \\ V_{DD} \times 0.3 \\ \hline 318 \\ \pm 10 \\ \end{array}$	V V kΩ μA
NP1, HPOS1 to HPOS4, High-level input voltage Low-level input voltage Pull-down resistor Input leakage current 4) Push-pull output pins: QF High-level output voltage	V_{IH} V_{IL} R_{IL} I_{LIL} $I_{CPV, OE}$ V_{OH}	$V_{I} = V_{DD}$ $V_{I} = V_{SS}$ EH, OEV1 to OEV3, POL, HOPE IDENTIFY TO THE PROOF OF VSS $I_{OH} = -1.9 \text{ mA},$ $V_{I} = V_{DD} \text{ or } V_{SS}$ $I_{OL} = 1.9 \text{ mA},$ $V_{I} = V_{DD} \text{ or } V_{SS}$	V _{DD} × 0.7 0 33 — OUT, VOUT		$\begin{array}{c c} V_{DD} \\ V_{DD} \times 0.3 \\ \hline 318 \\ \pm 10 \\ \hline \end{array}$	V V kΩ μA
NP1, HPOS1 to HPOS4, High-level input voltage Low-level input voltage Pull-down resistor Input leakage current 4) Push-pull output pins: QF High-level output voltage Low-level output voltage	V_{IH} V_{IL} R_{IL} I_{LIL} $I_{CPV, OE}$ V_{OH}	$V_{I} = V_{DD}$ $V_{I} = V_{SS}$ EH, OEV1 to OEV3, POL, HOPE IDENTIFY TO THE PROOF OF VSS $I_{OH} = -1.9 \text{ mA},$ $V_{I} = V_{DD} \text{ or } V_{SS}$ $I_{OL} = 1.9 \text{ mA},$ $V_{I} = V_{DD} \text{ or } V_{SS}$	V _{DD} × 0.7 0 33 — OUT, VOUT		$\begin{array}{c c} V_{DD} \\ V_{DD} \times 0.3 \\ \hline 318 \\ \pm 10 \\ \hline \end{array}$	V V kΩ μA

Note) *: The I_{DDS} associated with the V_{DD} applied to the oscillator pin XI shall be take from a power supply separate from the measured power supply.

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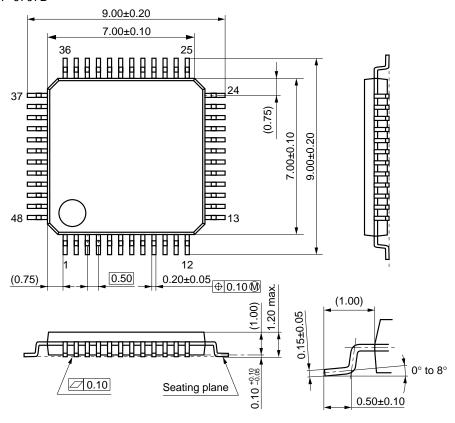
■ Electrical Characteristics (continued)

3. Electrical Characteristics at V_{DD} = 2.7 V to 3.6 V, V_{SS} = 0 V, f_{TEST} = 30 MHz, T_a = -40°C to +85°C (continued)

Parameter	Symbol	Condition	Min	Тур	Max	Unit		
6) Tristate output pins: STH1, STH2, STV1, STV2								
High-level output voltage	V _{OH}	$I_{OH} = -1.9 \text{ mA},$ $V_I = V_{DD} \text{ or } V_{SS}$	V _{DD} - 0.6	_	_	V		
Low-level output voltage	V _{OL}	$I_{OL} = 1.9 \text{ mA},$ $V_{I} = V_{DD} \text{ or } V_{SS}$	_	_	0.4	V		
Output leakage current	I _{LO}	V_{O} = High-impedance state, V_{I} = V_{DD} or V_{SS} , V_{O} = V_{DD} or V_{SS}	_	_	±5	μА		
7) Tristate output pins: PD								
High-level output voltage	V _{OH}	$I_{OH} = -3.8 \text{ mA},$ $V_I = V_{DD} \text{ or } V_{SS}$	V _{DD} - 0.6	_	_	V		
Low-level output voltage	V _{OL}	$I_{OL} = 3.8 \text{ mA},$ $V_{I} = V_{DD} \text{ or } V_{SS}$	_	_	0.4	V		
Output leakage current	I _{LO}	V_{O} = High-impedance state, V_{I} = V_{DD} or V_{SS} , V_{O} = V_{DD} or V_{SS}		_	±5	μА		

■ Package Dimensions (Units: mm)

• TQFP048-P-0707B



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